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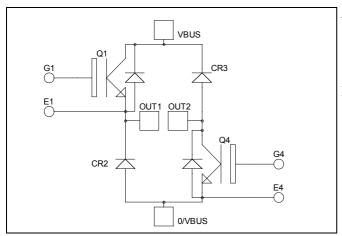






## Asymmetrical - Bridge Fast Trench + Field Stop IGBT3 Power Module





# OUT1 OUT1 OUT1 OUT2 OUT2

#### Application

- Welding converters
- Switched Mode Power Supplies
- Switched Reluctance Motor Drives

#### **Features**

- Fast Trench + Field Stop IGBT3 Technology
  - Low voltage drop
  - Low tail current
  - Switching frequency up to 20 kHz
  - Soft recovery parallel diodes
  - Low diode VF
  - Low leakage current
  - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
  - Symmetrical design
  - M5 power connectors
- High level of integration

#### Benefits

- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive TC of VCEsat
- Low profile
- RoHS Compliant

#### Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
$V_{CES}$	Collector - Emitter Breakdown Voltage		1200	V
$I_{C}$	Continuous Collector Current	$T_C = 25$ °C	280	
	Continuous Conector Current	$T_C = 80$ °C	200	A
$I_{CM}$	Pulsed Collector Current	$T_C = 25^{\circ}C$	400	
$V_{GE}$	Gate – Emitter Voltage		±20	V
$P_{\mathrm{D}}$	Maximum Power Dissipation	$T_C = 25$ °C	890	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 125$ °C	400A @ 1100V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



## All ratings @ $T_j = 25$ °C unless otherwise specified

## **Electrical Characteristics**

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
$I_{CES}$	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1200V$				350	μΑ
V	Collector Emitter Saturation Voltage	$V_{GE} = 15V$	$T_j = 25$ °C	1.4	1.7	2.1	V
$V_{CE(sat)}$	Conector Emitter Saturation Voltage	$I_C = 200A \qquad T_j = 125^{\circ}C$		2.0		·	
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$ , $I_C = 3 \text{ mA}$		5.0	5.8	6.5	V
$I_{GES}$	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				500	nA

**Dynamic Characteristics** 

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$ $V_{CE} = 25V$ $f = 1MHz$			14		
$C_{oes}$	Output Capacitance				0.8		nF
$C_{res}$	Reverse Transfer Capacitance				0.6		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (25°C) $V_{GE} = \pm 15V$ $V_{Bus} = 600V$ $I_{C} = 200A$ $R_{G} = 2.7\Omega$			260		ns
$T_{r}$	Rise Time				30		
$T_{d(off)}$	Turn-off Delay Time				420		
$T_{\mathrm{f}}$	Fall Time				70		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C) $V_{GE} = \pm 15V$ $V_{Bus} = 600V$ $I_{C} = 200A$ $R_{G} = 2.7\Omega$			290		ns
$T_{r}$	Rise Time				50		
$T_{d(off)}$	Turn-off Delay Time				520		
$T_{\mathrm{f}}$	Fall Time				90		
Eon	Turn on Energy	$V_{GE} = \pm 15V$ $V_{Bus} = 600V$	$T_j = 125$ °C		20		mI
$E_{\text{off}}$	Turn off Energy	$I_C = 200A$ $R_G = 2.7\Omega$	$T_j = 125$ °C		20		mJ

Reverse diode ratings and characteristics

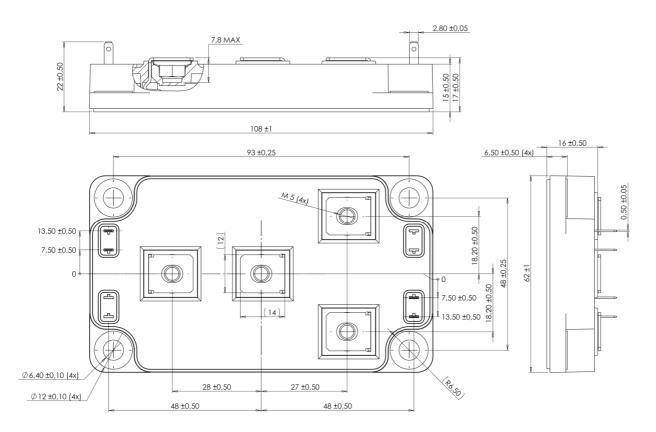
Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
$V_{RRM}$	Maximum Peak Repetitive Reverse Voltage			1200			V
$I_{RM}$	Maximum Reverse Leakage Current	V <sub>R</sub> =1200V	$T_i = 25$ °C $T_i = 125$ °C			350 600	μΑ
$I_{\mathrm{F}}$	DC Forward Current		$Tc = 80^{\circ}C$		200		A
V	V <sub>E</sub>   Diode Forward Voltage   1	$T_i = 25^{\circ}C$		1.6	2.1	V	
<b>v</b> <sub>F</sub>		$T_{i} = 125^{\circ}C$		1.6			
$t_{rr}$	Reverse Recovery Time	1 2004	$T_j = 25^{\circ}C$		170		ns
c <sub>II</sub>			$T_j = 125$ °C		280		115
0	$Q_{rr}$ Reverse Recovery Charge $V_R =$	$I_F = 200A$ $V_R = 600V$	$T_j = 25$ °C		18		μС
Qrr		$di/dt = 2500A/\mu s$	$T_j = 125$ °C		36		μС
E	E <sub>r</sub> Reverse Recovery Energy		$T_j = 25$ °C		10		ma I
$\mathbf{E}_{\mathrm{r}}$			$T_i = 125$ °C		18		mJ



## Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
$R_{thJC}$	Lunction to Case Thermal Resistance		IGBT			0.14	°C/W
1\(\text{thJC}\)			Diode			0.25	
$V_{ISOL}$	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz			4000			V
$T_{J}$	Operating junction temperature range Storage Temperature Range			-40		150	
$T_{STG}$				-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
		For terminals	M5	2		3.5	18.111
Wt	Package Weight	·	•			300	g

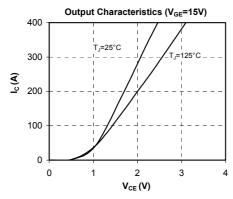
## SP6 Package outline (dimensions in mm)

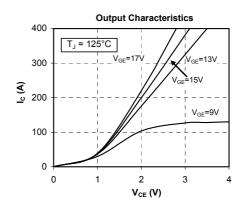


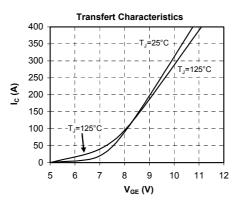
 $See \ application \ note \ APT0601 - Mounting \ Instructions \ for \ SP6 \ Power \ Modules \ on \ www.microsemi.com$ 

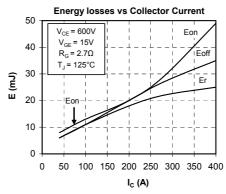


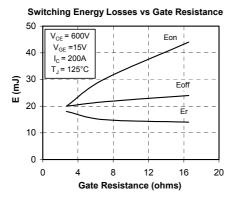
## **Typical Performance Curve**

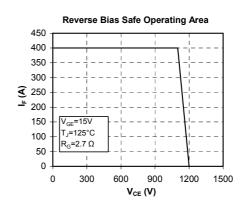


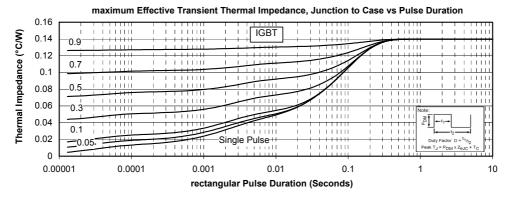




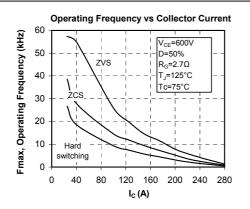


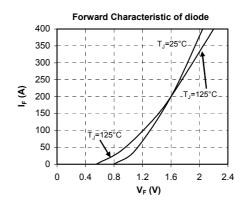


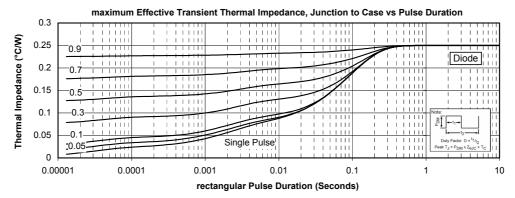












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